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Modified March C - Algorithm for Embedded Memory Testing

Muddapu Parvathi¹, N. Vasantha², K. Satya Parasad³

¹Department of Electronics and Communication , M.R.I.T.S, Hyderabad, India.
 ²Department of Information Technology, V.C.E, Hyderabad, India.
 ³Department of Electronics and Communication, J.N.T.U.K, Kakinada, India.

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ABSTRACT

March algorithms are known for memory testing because March-based tests are all simple and possess good fault coverage hence they are the dominant test algorithms implemented in most modern memory BIST. The proposed march algorithm is modified march c- algorithm which uses concurrent technique. Using this modified march c- algorithm the complexity is reduced to 8n as well as the test time is reduced greatly. Because of concurrency in testing the sequences the test results were observed in less time than the traditional March tests. This technique is applied for a memory of size 256x8 and can be extended to any memory size.

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Corresponding Author:

Muddapu Parvathi Departement of Electronics and Communication Engineering, Malla Reddy Institute of Technology and Science, Maisammaguda, Dhulapally, Secunderabad-500014, Andhra Pradesh, India. Email: pbmuddapu@gmail.com

1. INTRODUCTION

Embedded Memories are growing rapidly to a large amount in terms of its size and density. As embedded memories are using complex design structures the chances of occurring manufacturing defects is more compared to any other embedded core on SOC. Hence testing of embedded memory is a real challenge for design architect. For SOC the inability to have direct access to a core is one of the major problems in testing and diagnosis [1-4]. Further the available bandwidth between the primary inputs of the system chip and the embedded core is usually limited. Hence the external access for test purpose is often infeasible. This has prompted a very strong interest in self test of embedded arrays. In particular, functional March tests have found wide acceptance, mostly because they provide defined detection properties for classical memory array faults such as stuck at faults and transition faults.

Memory tests are used to confirm that each location in a memory device is working. This involves writing a set of data to each memory address and verifying this data by reading it back. If all the values read back are the same as those that were written, then the memory device is said to pass the test, otherwise device fails. Different test methodologies have been evolved from the years to identify the memory defects, one such test is memory built in self test which involves built in self test circuitry for each memory array.

The advantage of March tests lay in the fact that high fault coverage can be obtained and the test time were usually linear with the size of the memory which makes it acceptable from industrial point of view. March based algorithms were capable of locating and identifying the fault types which can help to catch design and manufacturing errors. Especially SAF dominate the majority of defects that occur in embedded RAMS.

The method proposed in this paper is Modified March C- algorithm with concurrent technique. This algorithm retains the high fault coverage of March C but at reduced time the tests can be done. The paper further describes the functional fault models in the memory, classical and March based tests in section II. The proposed Modified March c- algorithm was discussed in section III. Results and comparisons were discussed in section IV. Conclusions were given in section V.

2. HISTORY OF FUNCTIONAL FAULT MODELS

For testing purpose the functional fault models are modeled after faults in memories so that functional tests to detect these faults can be used. This modeling helps to clarify, simplify and generalize the testing approach of a memory. The quality of tests is strongly dependent on the fault model in terms of its fault coverage, its test length as well as the test time required.

There are various fault models to test the functional faults such as stuck at faults; coupling faults are considered when it deals with SRAM. Address decoder faults and bridging faults will be considered when it deals with DRAM. Hence the most possible faults which occur in general are stuck at faults [5-7].

Stuck at fault (SAF) : The stuck-at fault (SAF) considers that the logic value of a cell or line is always 0 (stuck-at 0 or SA0) or always 1 (stuck-at 1 or SA1). To detect and locate all stuck-at faults, a test must satisfy the following requirement: from each cell, a 0 and a 1 must be read.

Transition Faults(TF): The transition fault (TF) is a special case of the SAF. A cell or line that fails to undergo a $0 \rightarrow 1$ transition after a write operation is said to contain an up transition fault. Similarly, a down transition fault indicates the failure of making $1 \rightarrow 0$ transitions. According to van de Goor [8, 9], a test to detect and locate all the transition faults should satisfy the following requirement: each cell must undergo an \uparrow transition (cell goes from 0 to 1) and a \downarrow transition (cell goes from 1 to 0) and be read after each transition before undergoing any further transitions.

The fault detection for both SAFs and TFs will be done by considering MATS++ algorithm and March C- algorithm. Although different in test length, these tests are capable of detecting both faults while being capable of detecting other faults as well. The detection process can be understood by examining the Mach C- algorithm as indicated in expression below.

March Test Notation: A March test consists of a finite sequence of March elements [10-12]. A March element is a finite sequence of operations or primitives applied to every memory cell before proceeding to next cell. For example, \downarrow (r1, w0) is a March element and r0 is a March primitive. The address order in a March element can be increasing (\uparrow), decreasing (\downarrow), or either increasing or decreasing (\uparrow). An operation can be either writing a 0 or 1 into a cell (w0 or w1), or reading a 0 or 1 from a cell (r0 or r1). Accordingly notation of March C- test is described as follows:

$\{\uparrow(w0);\uparrow(r0,w1);\uparrow(r1,w)\}$	0);↓(r0,w1);↓(r1,w0); (r0)}
---	-------------------------------------

\downarrow	\downarrow	\downarrow	\downarrow	\downarrow	\downarrow
M_{I}	M_{II}	$\mathbf{M}_{\mathbf{III}}$	M_{IV}	$\mathbf{M}_{\mathbf{V}}$	M_{VI}
rithm has 6 a	lamonte ac	chown with	h a compla	vity of 10)n

March C- algorithm has 6 elements as shown with a complexity of 10n.

3. MODIFIED MARCH C- ALGORITHM

The proposed Modified March C- algorithm almost similar to March C- but it follows concurrency in testing the sequences. The steps for following the concurrency are as follows:

•Group entire memory into subgroups.

•For each subgroup, generate all test vectors for the first fault in the group.

•Simulate all faults in the subgroup to select one vector that detects most faults in that

subgroup. If more vectors than one detect the same number of faults within the group,

then select the vector that detects most faults outside the group as well.

•Apply the final test vectors to all subgroups concurrently

In the proposed method the memory is divided in to two subgroups such as M1 and M2. Then applied the algorithm for concurrency. The following are the elements in Modified March C- algorithm.

M1: { \uparrow (w0); \uparrow (r0,w1); \uparrow (r1); \downarrow (w0); \downarrow (r0,w1); \downarrow (r1); M2: { \uparrow (w1); \uparrow (r1,w0); \uparrow (r0); \downarrow (w1); \downarrow (r1,w0); \downarrow (r0);

The number of March elements is same as traditional March c- and is 6 but because of concurrency the complexity is reduced to 8n.

The pseudo code for modified march c- is as follows:

```
//for writing 0s in block 1 and writing 1s in block 2, let n and m are rows and columns
   for(i=0;i<(n-1)/2;i=i+1)
      begin
           for(j=0;j<(m-1);j=j+1)</pre>
               mem[i][j]=0;//write 0 in m1
     end
for(i=(n-1)/2;i<(n-1);i=i+1)
    begin
            for (j=0; j<(m-1); j=j+1)
               mem[i][j]=1;//write 1 in m2
    end
//for reading background and for writing
                                                alternate
            for(i=0;i<(n-1)/2;i=i+1)
                 begin
               for(j=0;j<(m-1);j=j+1)</pre>
                  begin
                       if(mem[i][i]==0)
                      mem[i][j]=1;
                      else return;
                end
         end
     for(i=(n-1)/2;i<(n-1);i=i+1)
           begin
               for(j=0; j < (m-1); j=j+1)
                  begin
                       if(mem[i][j]==1)
                      mem[i][j]=0;
                      else return;
                end
         end
```

According to Modified March C- elements, when 0s are written in one memory group, 1s will be written in another group concurrently. So the test sequence can be taken through an inverter hence true form will goes to one block of memory and complement form will goes to another block of memory. Hence the test sequence generator requires additionally one inverter in order to perform test concurrently. The method directly reduces the time required to write and read the bit concurrently. This reduces the test time and test costs also. Finally, there may be additional design cost in terms of inverter only which need to generate complement test sequence to other part of the memory block.

4. **RESULTS AND COMPARISIONS**

Table 1 indicates delay performance for each element present in traditional March C- algorithm given for fault free condition and faulty condition. Under faulty condition using SA fault models the overall delay observed as 13.782ns.

Table 2 shows the delay performance using Modified March C- algorithm. In this also delay performance were calculated separately for fault free as well as faulty conditions. Under faulty condition the overall delay was observed as 11.784ns. Hence it is proved that using Modified March C- algorithm using concurrency the overall delay is greatly reducing. It is giving at speed test performance than any other traditional algorithm. The result tables also provide the information on minimum input arrival time before clock and maximum output time after the clock. Simulation was carried using Xilinx ISE 10.1i tool for the device XC3S4004tq144 and tested on Spartan 3 kit. Fig 1 and 2 shows the simulation results respectively for modified march elements I and II when fault is imposed.

Table 1. Results for Traditional March C- Algorithm												
	MINIMUM PERIOD IN MINIMUM INPUT ARRIVAL TIME BEFORE MAXIMUM OUTPUT REQUIRED TIME AF											
MARCH	NANO	SEC	CLOCK IN NA	ANO SEC	CLOCK IN NANO SEC							
ELEMENT	WITH NO	WITH	WITH NO FALLT	WIVH FALLT	WITH NO FALLT	WIVH EATH T						
	FAULT	FAULT	WITH NO FAULT	WITHFAULI	WITH NO FAULT	WITHFAULI						
M _I :‡(w0)	1.483	2.075	3.439	4.033	6314	628						
M_{II} : $(R0, W1)$	1.585	2.085	3504	3529	6318	6314						
M _{III} : ↑(R1,W0)	1.585	2.085	3.504	3.529	6.318	6.314						
M_{IV} : \downarrow (R0,W1)	1.585	2.085	3.504	3.529	6.318	6.314						
$M_V: \downarrow (R1, W0)$	1.585	2.085	3.504	3.529	6.318	6.314						
$M_{\rm VI}$: \uparrow (R0)	2.196	3.367	3.955	4.170	6318	63						

1 0 11

Table 2. Results for Modified March C- Algorithm											
	MINIMUM F	ERIOD IN	MINIMUM INPUT ARRI	VAL TIME BEFORE	MAXIMUM OUTPUT REQUIRED TIME AFTER						
MARCH	NANO	SEC	CLOCK IN N.	ANO SEC	CLOCK IN N.	OCK IN NANO SEC					
ELEMENT	WITH NO	WITH	WITH NO FAULT	WIYH FAULT	WITH NO FAULT	WIYH FAULT					
	FAULT	FAULT									
M1: ↑(W0)	1.483	2.111	3.439	3.473	631	628					
M2:↑(W1)											
M1:↑(R0,W1)	2.132	2.196	4.755	3979	628	6441					
M2: [†] (R1,W0)											
M1: ↑(R1)	2.132	1.585	3.96	3.50	6.28	6.318					
M2:↑(R0)											
M1:↑(W1)	1.483	2.111	3.439	3.473	6.31	6.28					
M2: (w0)											
$M1:\downarrow(R0,W1)$	2.132	2.196	4.755	3979	6.28	6.441					
M2:↓(R1,W0)											
$M1: \downarrow (R1)$	2.132	1.585	3.96	3.50	6.28	6.314					
M2:↓(R0)											

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I able	э.	Comparison	

COMPLEXITY	DELAY (NANO SEC)
10N	13.782
8N	11.783
	COMPLEXITY 10n 8n

		0.007 ns							
Name	Value	0 ns		20 ns	40 ns	60 ns	180 ns	100 ns	120 ns
🔚 clk	0								
🚡 en	0								
퉵 wr	0								
퉵 rd	0								
🕨 📷 ad[1:0]	00			00		01		10	
🕨 📷 di[3:0]	0000				/000				1111
> 🐻 add[3:0]	XXXX	XXXX		0001		0000	X	1111	
▶ 式 dout[3:0]	XXXX		XXXX		0001		0000		1111

Figure 1. Simulation results for modified march C- element I $\{M1:\uparrow(w0)\}\{M2:\uparrow(w1)\}$

Current Simulation Time: 1000 ns		0 ns I	s : 	25 n: 1	s 50) ns 	7	′5 n s	100 	ns II	125 r	ns 15	i0 ns	1	75 n I	IS I I I	200	ns II	22
õn cik	1																		
an 🔁	1																		
on wr	0																		
👌 🛛 rd	1																		
🗉 🚮 ad[1:0]	2'b11			2'b0(0	X	2'b	01	Χ	2'b	10	X				2'b	11		
🖿 🚮 di[3:0]	4				4'b00	00			Χ					4'b1	111				
🖬 🚮 add[3:0]	4	4			4 ⁻ b	0000	$\overline{}$	<u></u>	Χ				Γ	4'b1	111		\		
🖽 🚮 addr[3:0]	4	4			4'b	1111			X					4'b0	000				
🗉 刻 dout[3:0]	4	4		XX)			4'b0	000							4'b1	111/	,		

Figure 2. Simulation results for modified march C- element II $\{M1:\uparrow(r0,w1)\}\{M2:\uparrow(r1,w0)\}$

5. CONCLUSION

This paper defines the functional fault model and compared the traditional march c- algorithm with modified march c- algorithm in terms of speed of the test sequence and complexity of the number of test sequences. The crucial part in testing is how well the test can be completed in minimum time with minimal test length. The modified march algorithm has proved that the test length is minimal as well as the time required to test SAF also minimum when compared with traditional march c-. Hence this modified march c- is much comparable and could be used for detection of various faults other than SAF as future work.

REFERENCES

- [1] Shibaji Banerjee, Dipanwita Roy Chowdhury and Bhargab B. Bhattacharya, in proceedings of the 2005 IEEE International Workshop on Memory Technology, Desgin and Testing (MTDT'05).
- [2] The national Roadmap for Semiconductors, 2000. Semiconductor Industry Association.
- [3] E Eric Dupont, Michael Nicolaidis, and Peter Rohr, "Embedded Robustness IPs forTransient Error free ICs", IEEE Design & Test of Computers, 2002.
- [4] Dupont, E. Nicolaidis, M. And Rohr .P. "Embedded Robustness IPs for Transient Error Free ICs" IEEE Design & Test of Computers, Vol 19, No 3, pp 56-70, May-June, 2002.
- [5] J.F.Li, K.L.Cheng, C.T.Huang, and C.W.Wu, "March based RAM diagnostic algorithms for stuck-at and coupling faults", Proc, IEEE ITC pp, 758-767, 2001
- [6] Y. Yorozu, M. Hirano, K. Oka, and Y. Tagawa, "Electron spectroscopy studies on magneto-optical media and plastic substrate interface," IEEE Transl. J. Magn. Japan, vol. 2, pp. 740–741, August 1987 [Digests 9th Annual Conf. Magnetics Japan, p. 301, 1982].
- [7] R. Dekker, F. Beenaker, L. Thijssen, "A realistic fault model and test algorithm for static random access memories", IEEE Trans. Computer-Aided Design, vol,9,99.567-572, june 1990.
- [8] J. van de Goor. Testing Semiconductor Memories: Theory and Practice.A.J.vandeGoor,1998.
- [9] Verilog Digital System Desigh, 2nd Edition, Zainalabedin Navabi, Tata McGraw Hill, 2008
- [10] A.J.Van de Goor, Testing Semiconductor Memories, Theory and Practice, John Wiley & Sons, Chichester, England, 1991.
- [11] Van De Goor, A.J. Sehanstra. I., "Address and Data Scrambling: Causes and Impact on Memory Tests", IEEE DELTA Workshop, Christchurch, January 2002.
- [12] ER.Manoj Arora, Er.Shipra Tripathi, "Comparative Simulation of MBIST using March Test Algorithms", International Journal of Scientific & Engineering Research, Volume 2, Issue 12, December-2011.

BIOGRAPHIES OF AUTHORS



M. Parvathi has done her B.Tech in Electronics and Communication Engineering fro N.I.T.Warangl,A.P, India. She ghas done her M.Tech in the specialization Digital Systems and Computer Electronics from JNTUH, A.P, India. Presently She is serving as Associate Professor in the Department of Electronics and Communication since 11 years. She is pursusing her Ph.D in the field of VLSI Design from JNTUK, Kakinada, A.P, India.Her areas of interests are Micro Electronics, VLSI Design, Digital Design, Micro Processors and Embedded Systems. She is Member of IEEE and Life Member of IETE and ISTE Technical Societies. She has published few Science and Technical papers in various International and National reputed Journals an Conferneces.



N. Vasantha Garu has done her B.E from College of Engineering, Guindy, Madras University and M.Tech in Advanced Electronics from JNTUH, Hyderabad, AP, India. She received her Doctorate in ECE in the field of VLSI Design from Osmania University. She is serving as Head of the Department of I.T and has more than twenty years of experience in teaching. She is senior member of IEEE and life member of IETE and ISTE Technical Societies. She has published more than twenty Science and Technical papers in various International and National reputed journals and conferences.



K. Sathya Prasad Garu was born in 1955 in Kakinada, Andhra Pradesh, India. Since 1980 he is in service of Teching Profession and presently he is serving as Rector in J.N.T.U.K, Kakinada, Andhra Pradesh, India. He guided 13 Ph.D Scholars. He was author of text book Electronics Devices and Circuits. He is member of Technical Societies such as IEEE, and life member of IETE and ISTE and Fellow member of IE. He organized as convener over 8 conferences. He has 17 publications in various national and international journals. His areas of interest are Signals Systems, Communications, DSP.